

Superconducting High-Resolution X-Ray Spectrometers for Chemical State Analysis of Dilute Samples

Stephan Friedrich

QuickTime™ and a
BMP decompressor
are needed to see this picture.



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Outline: Why Cryogenic Detectors?

- Why low T? 
 - Low thermal noise
 - Small excitation energies

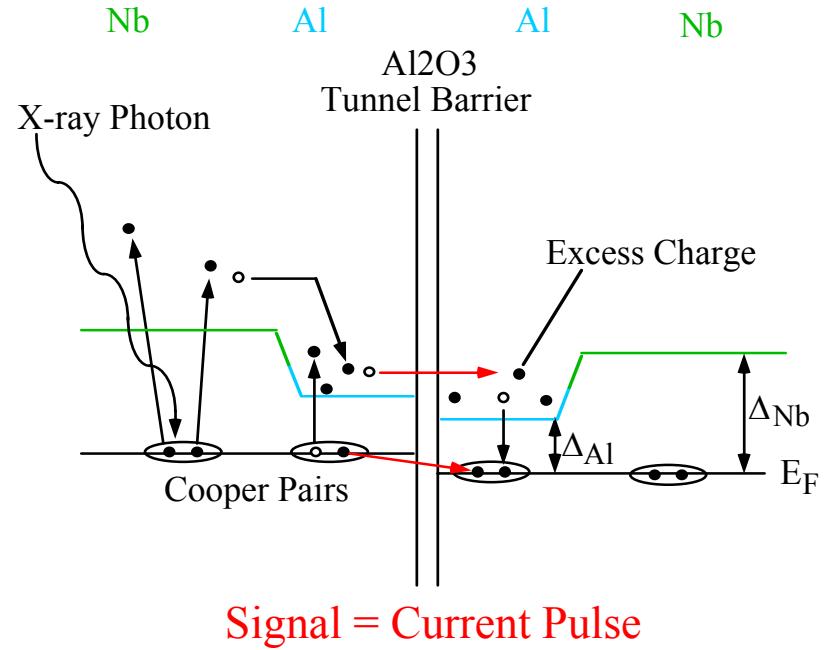
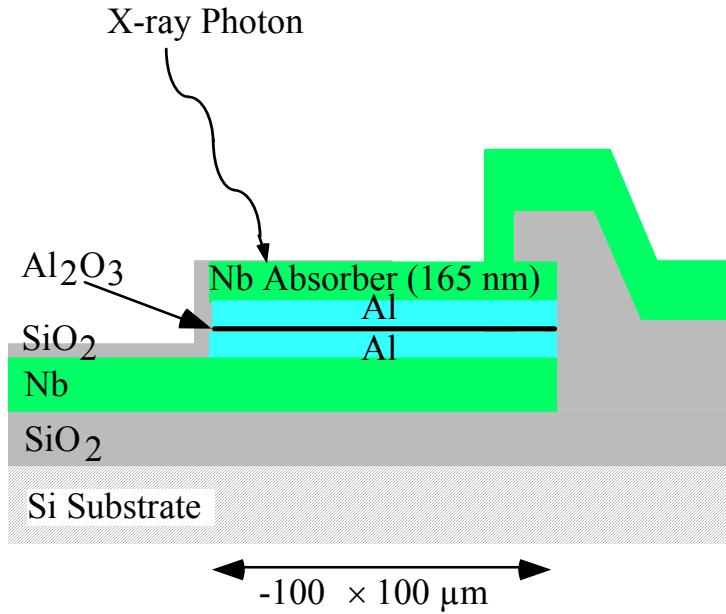
High energy resolution
- Which technologies?

	Tunnel Junctions	Microcalorimeters
Operating Principle	$E \rightarrow \Delta Q$	$E \rightarrow \Delta T$
Resolution (0.1 to 6 keV)	2 - 12 eV FWHM	2 - 5 eV FWHM
Max. count rate	~10,000 cts/s	~500 cts/s

Both detectors have small pixel sizes ($\sim 0.2 \text{ mm}$)² and are operated around 0.1 K.

- What for?
 - Fluorescence-detected absorption spectroscopy of dilute samples

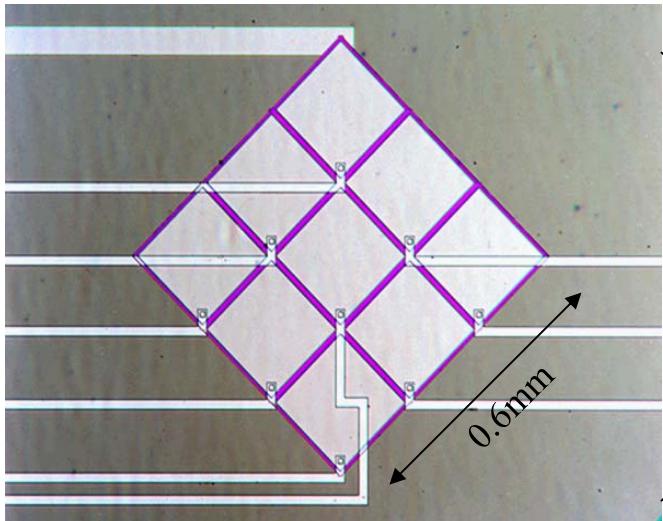
Superconducting Tunnel Junction Detectors



Small energy gap ($\Delta \approx 1 \text{ meV}$) \Rightarrow High energy resolution ($\approx 10 \text{ eV FWHM}$)
Short excess charge life time (μs) \Rightarrow (Comparably) high count rate ($\approx 10,000 \text{ counts/s}$)

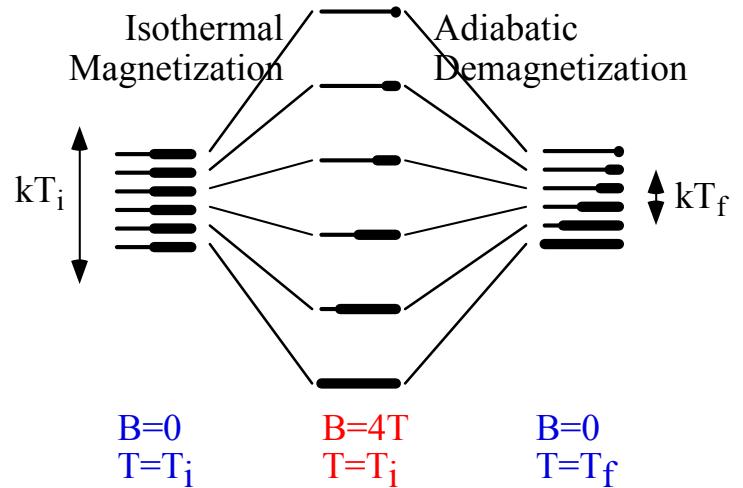
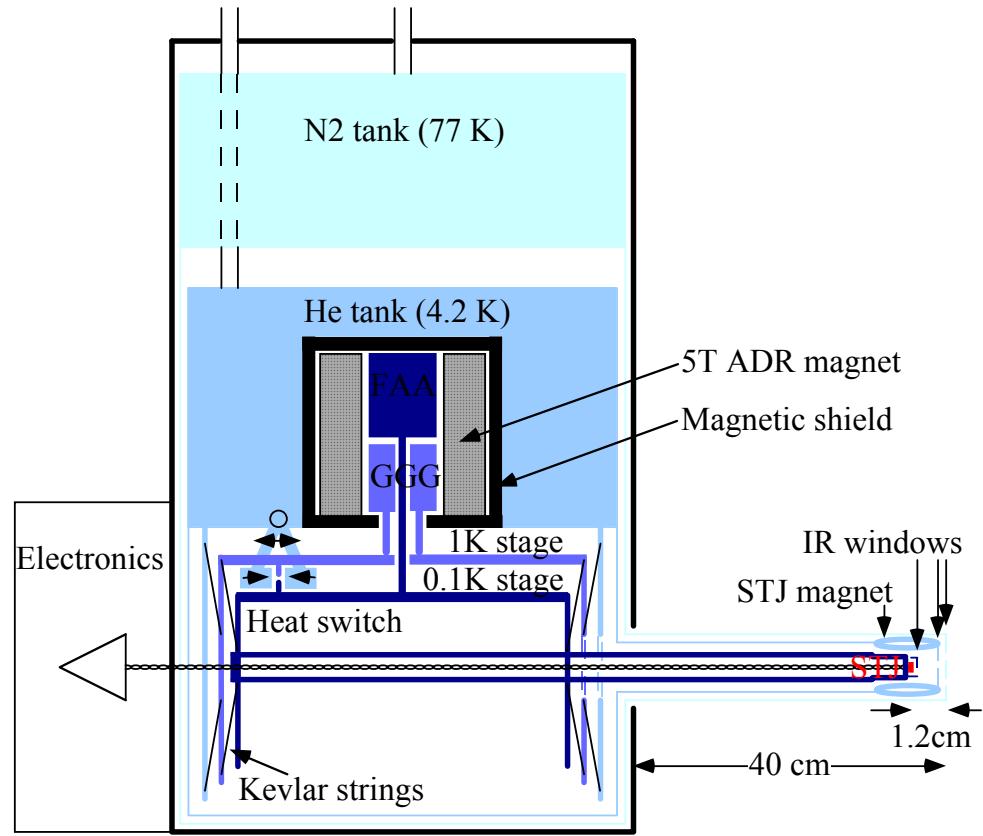
Two-Stage ADR with Cold Finger

- 70 mK base T, 20h below 0.4K
- 3×3 array at \approx 15mm $\Rightarrow \Omega/4\pi \approx 10^{-4}$
- \approx 15eV FWHM, >100,000 cts/s max



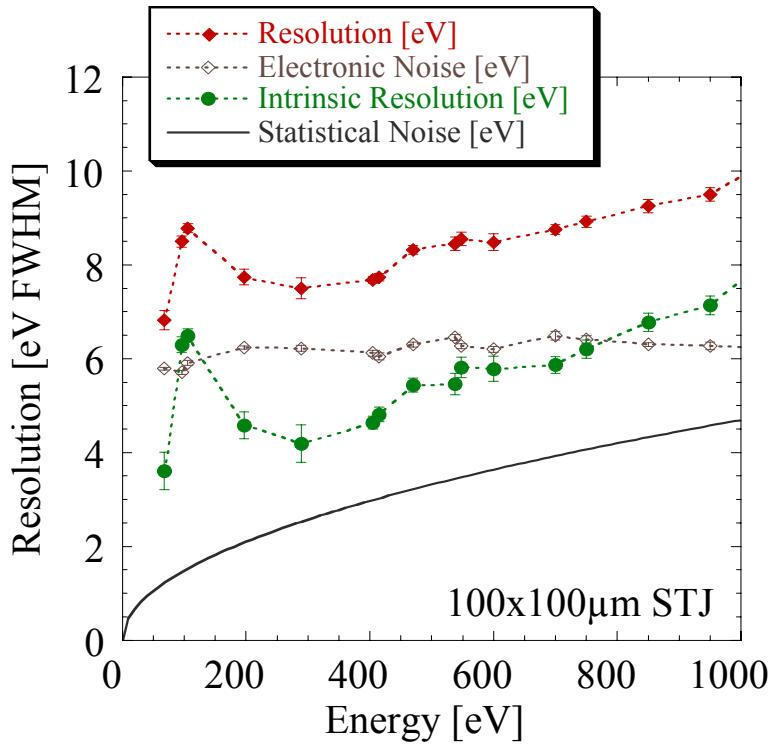
Inside this issue:
Focus on Coherent X-rays
and New Sources

Adiabatic Demagnetization Refrigeration

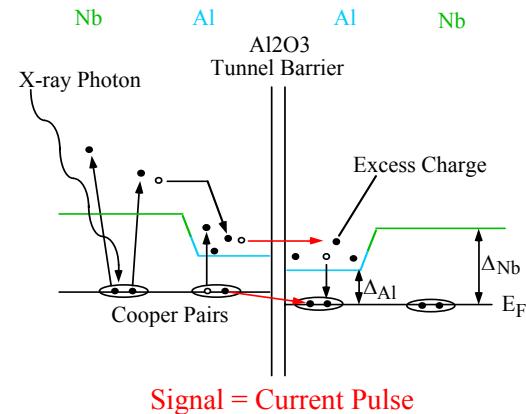


- 1) Close heat switch
- 2) Apply B (lower entropy S)
- 3) Open heat switch (decouple T)
- 4) Reduce B slowly (keeping entropy constant \Rightarrow reduce T)

STJ Performance: Energy resolution



$\leq 10\text{ eV}$ resolution below 1keV



Statistical limit:

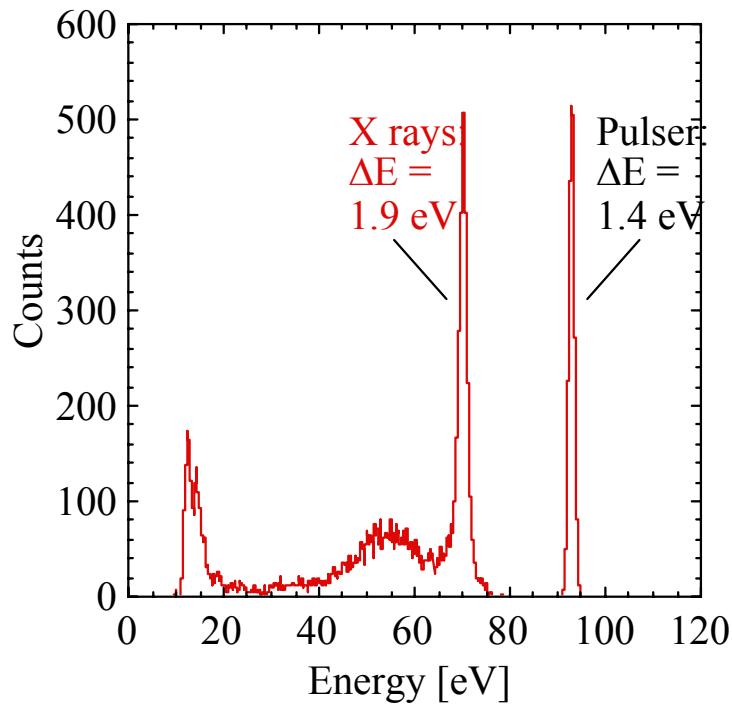
$$\Delta E_{FWHM} = 2.355 \sqrt{\varepsilon E_x (F + 1 + 1/\langle n \rangle)}$$

$\varepsilon \approx 1.7\Delta \approx \text{meV}$ = charge creation energy

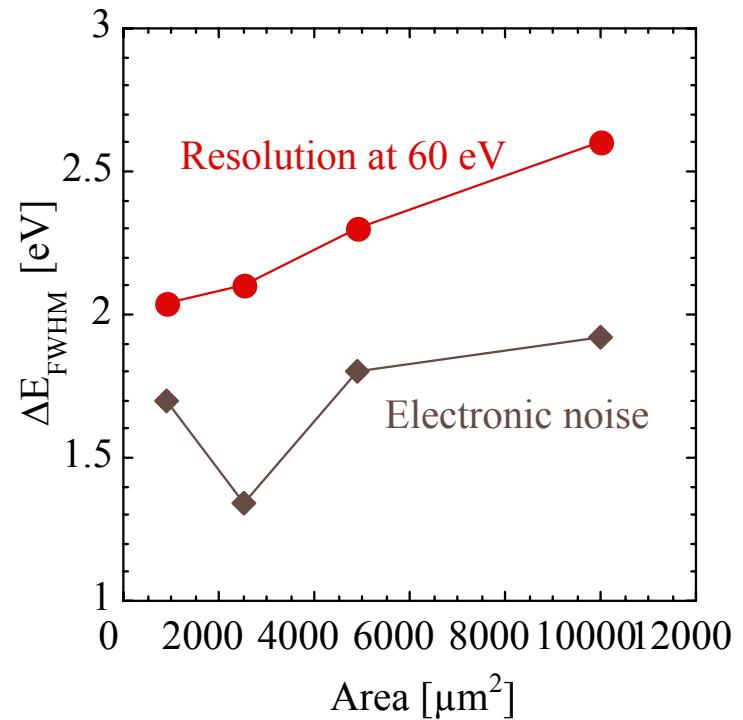
F = Fano factor (charge generation noise)

$1 + 1/\langle n \rangle$ = charge tunneling noise

STJ Performance: Area Dependence

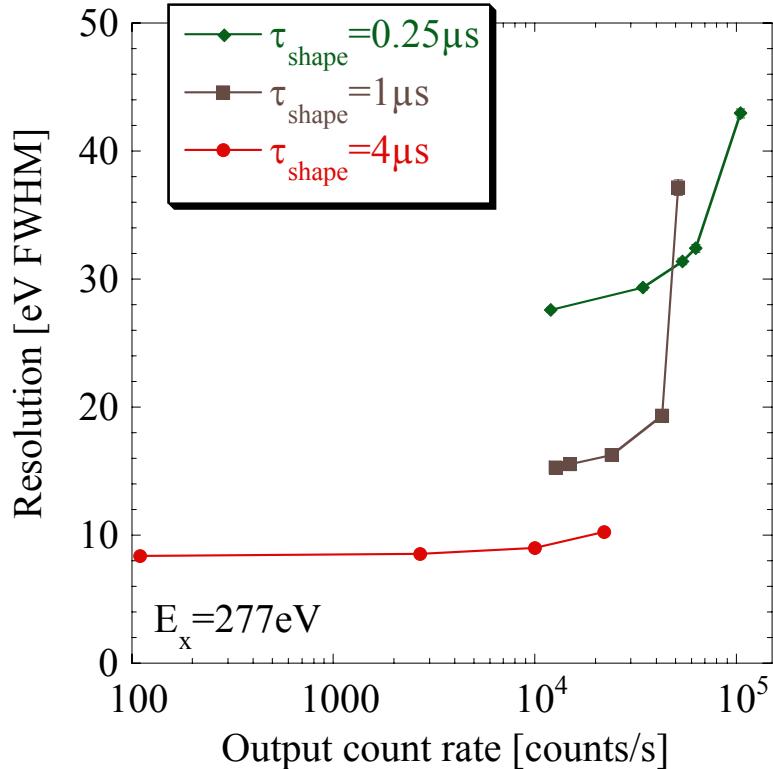


Low energy operation possible

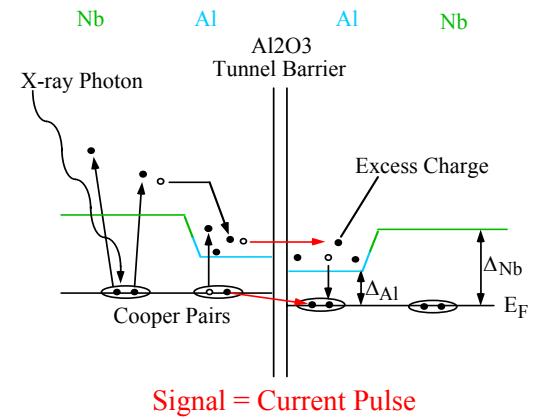


Trade-off between area and resolution

STJ Detector Performance: Count Rate

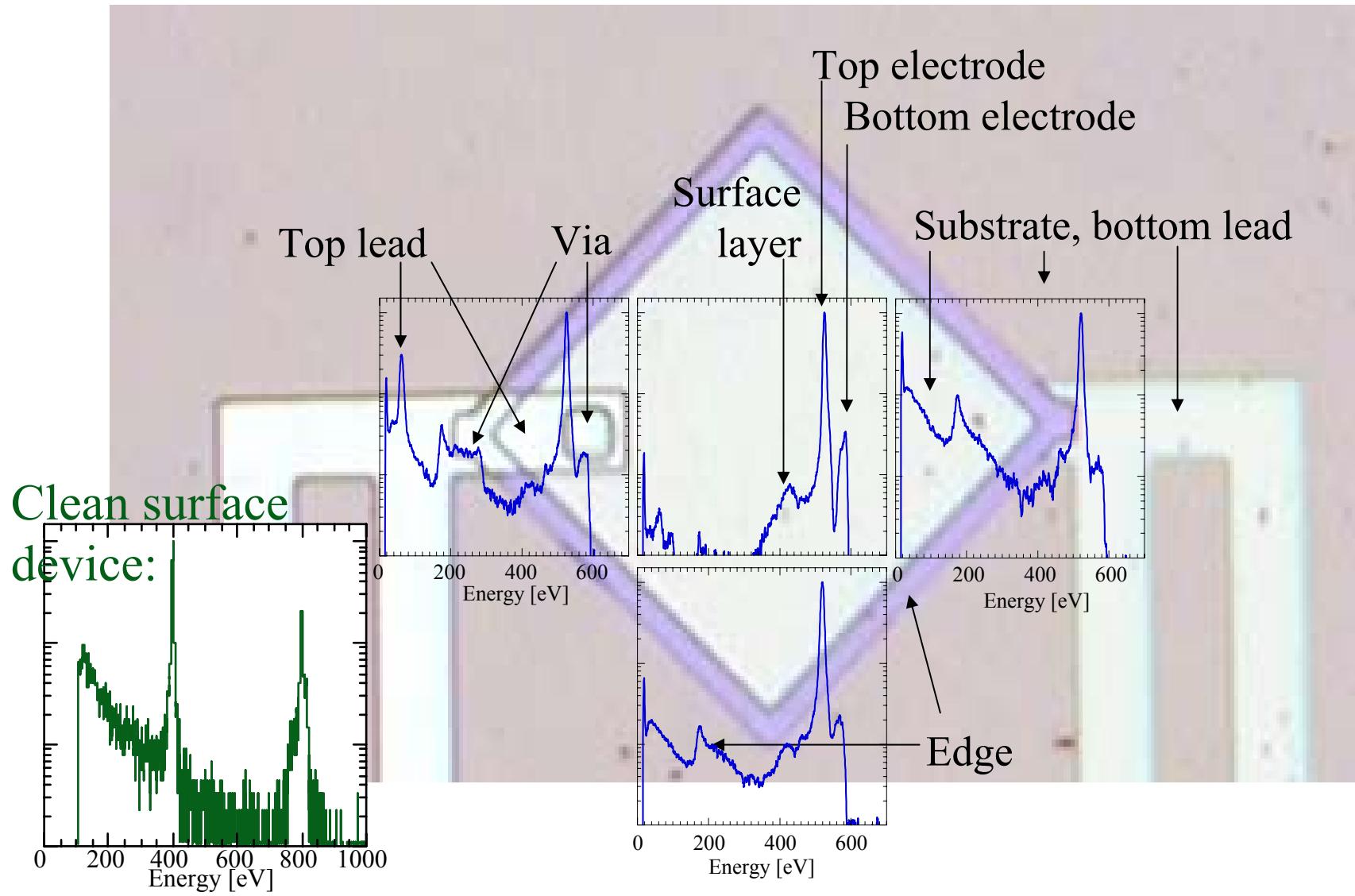


$\geq 10,000$ counts/s throughput

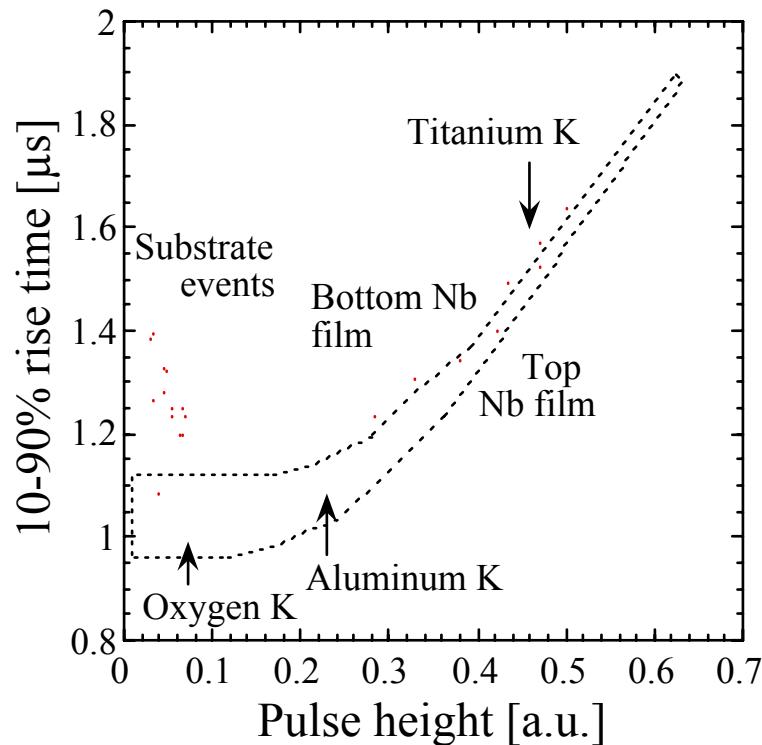


Current sensitive preamplifier :
 $\tau_{decay} = \tau_{life\ time} = \sim \text{few } \mu s$

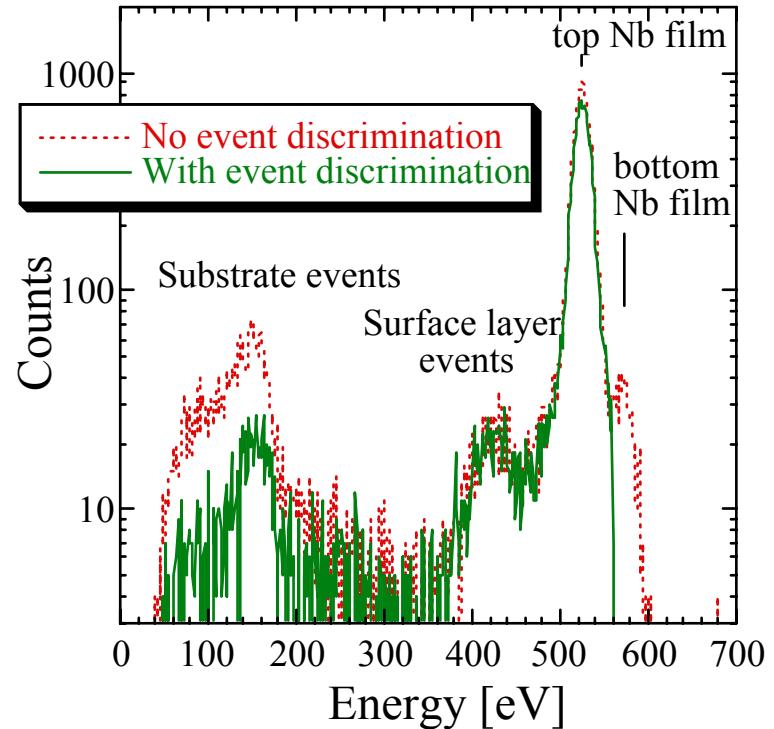
STJ Detector Performance: Lineshapes



Digital Signal Processing



Rise time differences between top and bottom electrode and substrate

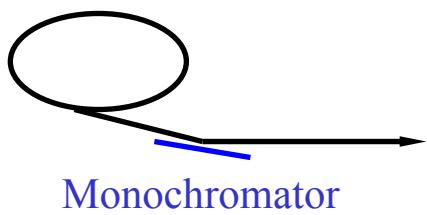


On-line event discrimination at 5000 cts/s to reduce artifacts

X-Ray Absorption Spectroscopy

Synchrotron beam

Intense, monochromatic, tunable
 $I_0 \approx 10^{12}$ photons/s
 $\Delta E = 0.1\text{ eV}$



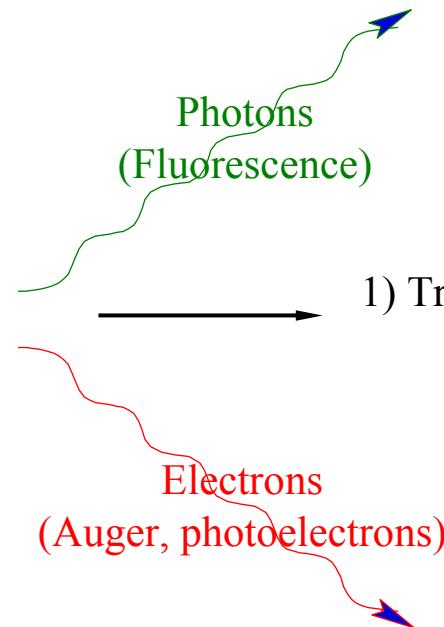
Sample x

Absorption $\mu_x(E)$



Detection

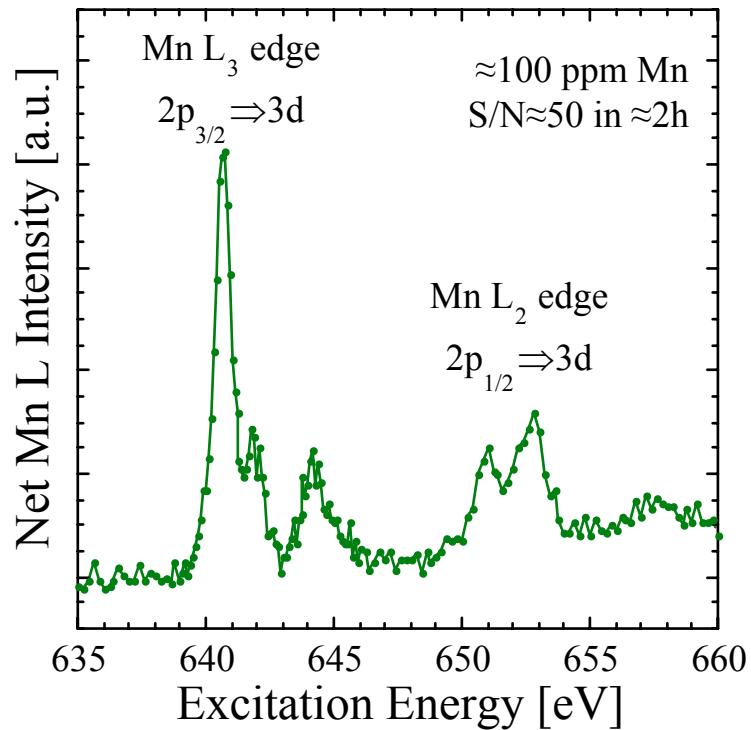
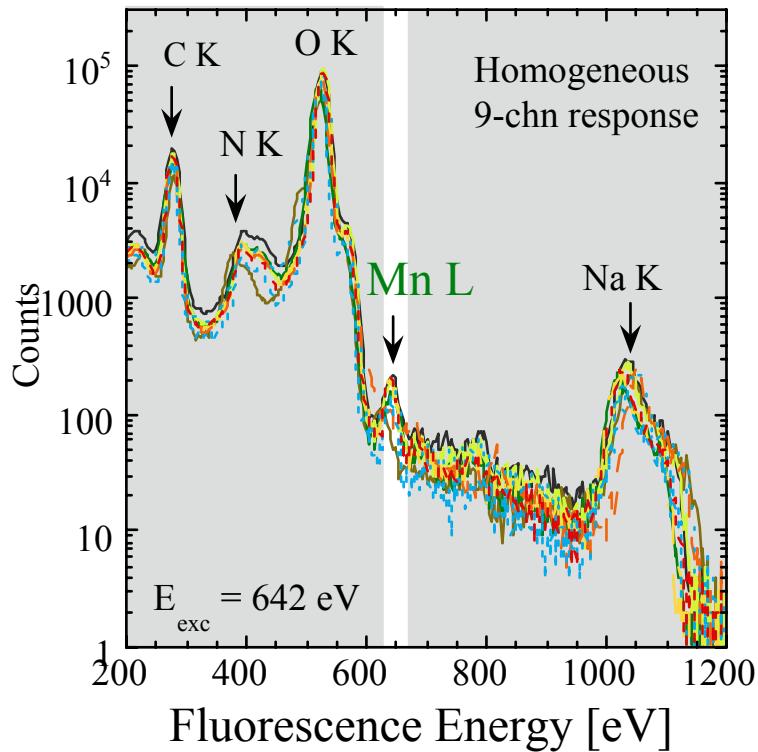
3) Fluorescence $\propto I_0 \cdot \mu_x(E)$



1) Transmission $\propto I_0 (1 - \mu_x - \mu_{\text{bkgd}})$
Thin samples
High background

2) Electron signal $\propto I_0 \cdot \mu_x(E)$
Surface sensitive
Moderate background

X-Ray Absorption Spectroscopy on Proteins

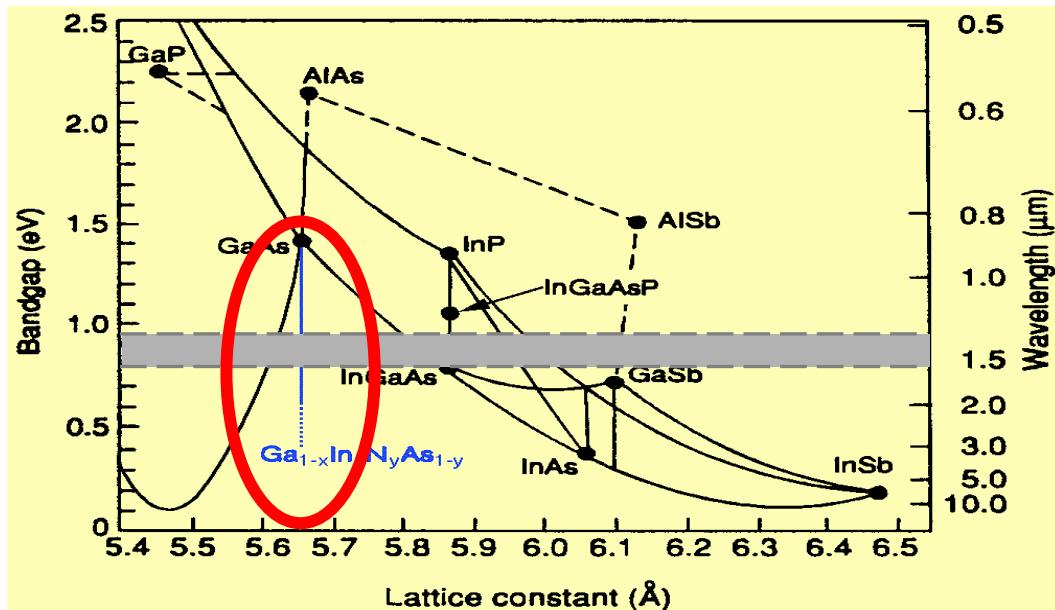


Spectrometer sufficiently sensitive for few ~100 ppm sample analysis.

Spectroscopy on active metal sites in proteins (photosystem II)

GaInNAs: A material for 1.3-1.55 μ m lasers

Collaboration with V. Lordi from Prof. Harris' group at Stanford



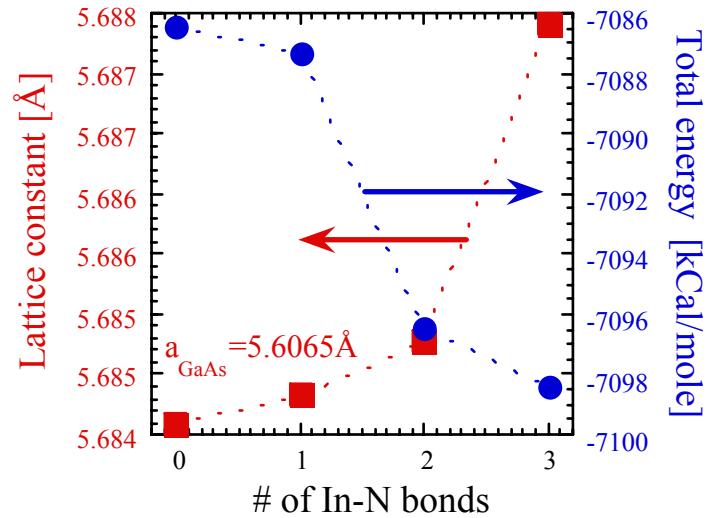
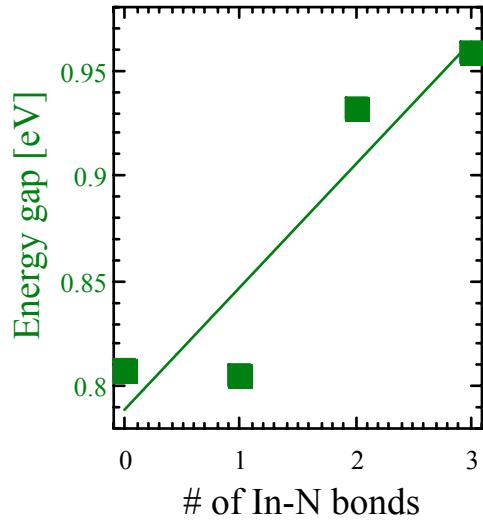
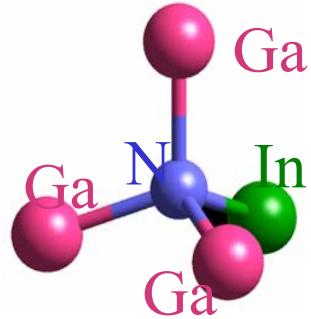
Telecommunications Application

- $Ga_xIn_{1-x}N_yAs_{1-y}$ ($x \approx 0.70$, $y \approx 0.03$) has a bandgap of $\sim 1.3 - 1.55 \mu\text{m}$
- It is nearly lattice-matched to GaAs
- Fabrication of inexpensive surface-emitting lasers for optoelectronics
- Optical fibers best at $\sim 1.3 - 1.55 \mu\text{m}$

Anneal GaInNAs to increase luminescence.

Problem: Band gap increases upon annealing

Nitrogen nearest neighbors affect optical properties

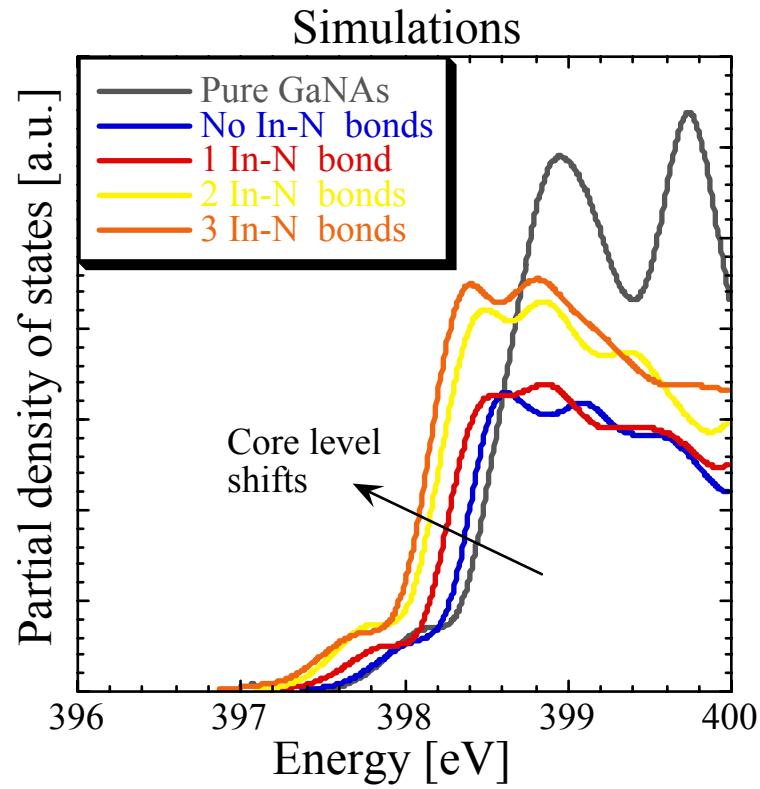
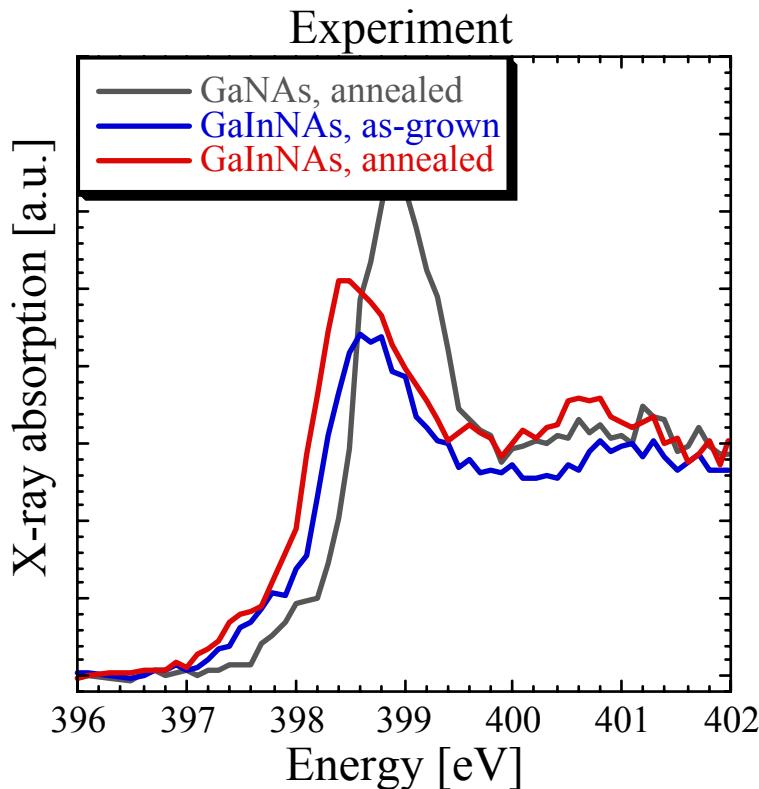


- MBE, ~2% nitrogen
- III-V random alloy
- FCC lattice
- Anneal at 780 °C, 1min
⇒ Luminescence increases
⇒ Bandgap increases

- Energy gap increases with # of In-N bonds

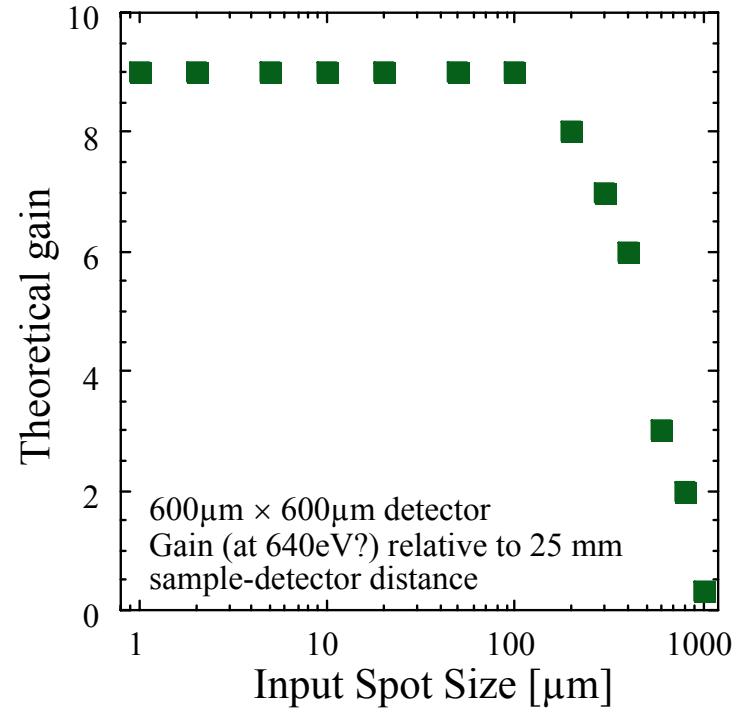
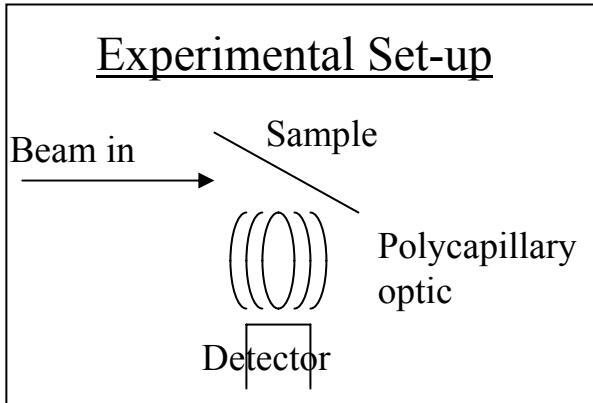
- Strain favors decreasing # of In-N bonds
- Thermodynamics favors increasing # of In-N bonds

Nitrogen X-ray absorption fine structure



Absorption edge shifts show increasing number of N-In bonds
Nitrogen migrates towards Indium upon annealing

Current/ Future Work: Enhance Sensitivity



Spectrometer Development:

- Polycapillary Optic (courtesy XOS)
- Larger Arrays (6×6)
- Ta absorber for efficiency at higher E

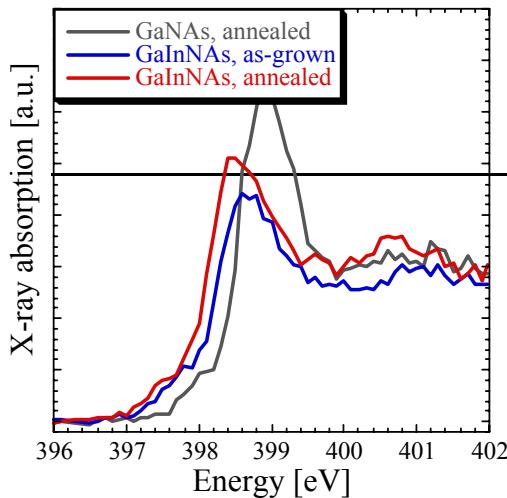
Summary

9-Channel STJ Detector Array

- <10-20 eV FWHM below 1keV
- >100,000 counts/s total count rate

ADR Cryostat with Cold Finger

- 70 mK Base T,
- 20h hold time below 0.4K



Fluorescence-Detected XAS on Dilute Samples

- Few 100 ppm samples with S/N \approx 50 in \approx 1hour
- Protein biochemistry and material science

Current/ Future Work: Increase Sensitivity

- Larger arrays, Closer, Ta absorbers, Optics...